



20N60

Power MOSFET

20A, 600V N-CHANNEL POWER MOSFET

■ DESCRIPTION

The UTC **20N60** is an N-channel enhancement mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology is specialized in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

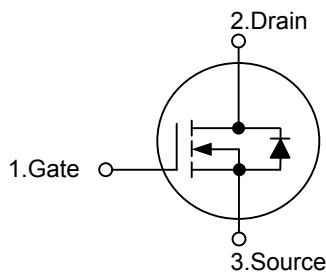
The UTC **20N60** is universally applied in motor control, UPS, DC choppers and switch-mode and resonant-mode power supplies.

■ FEATURES

* $R_{DS(ON)} = 0.45\Omega @ V_{GS} = 10V$

* High switching speed

■ SYMBOL

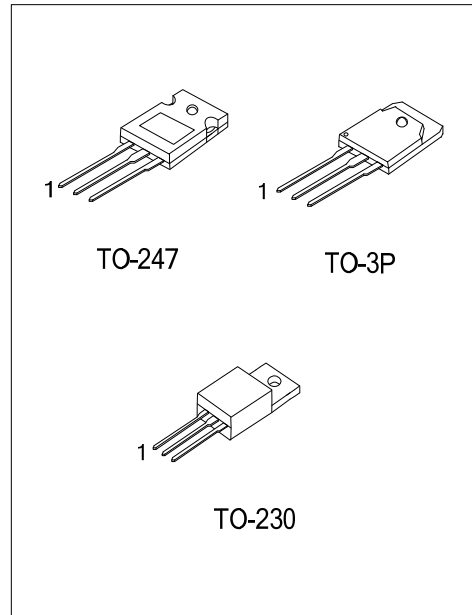


■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
20N60L-T47-T	20N60G-T47-T	TO-247	G	D	S	Tube
20N60L-T3P-T	20N60G-T3P-T	TO-3P	G	D	S	Tube
20N60L-TC3-T	20N60G-TC3-T	TO-230	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>20N60L-T47-T</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Lead Free</p>	<p>(1) T: Tube</p> <p>(2) T47: TO-247, T3P: TO-3P, TC3: TO-230</p> <p>(3) L: Lead Free, G: Halogen Free</p>
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■ ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	± 20	V
Drain Current	Continuous	I_D	20	A
	Pulsed	I_{DM}	80	A
Avalanche Energy	Single Pulsed(Note 2)	E_{AS}	1200	mJ
Power Dissipation	TO-247	P_D	370	W
	TO-3P		416	
	TO-230		260	
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55~+150	$^\circ\text{C}$

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. $V_{DD}=50\text{V}$, Starting $T_J=25^\circ\text{C}$, Peak $I_{AS}=20\text{A}$, $L=6\text{mH}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-247	θ_{JA}	40	$^\circ\text{C/W}$
	TO-3P		30	
	TO-230		62.5	
Junction to Case	TO-247	θ_{JC}	0.34	$^\circ\text{C/W}$
	TO-3P		0.3	
	TO-230		0.48	

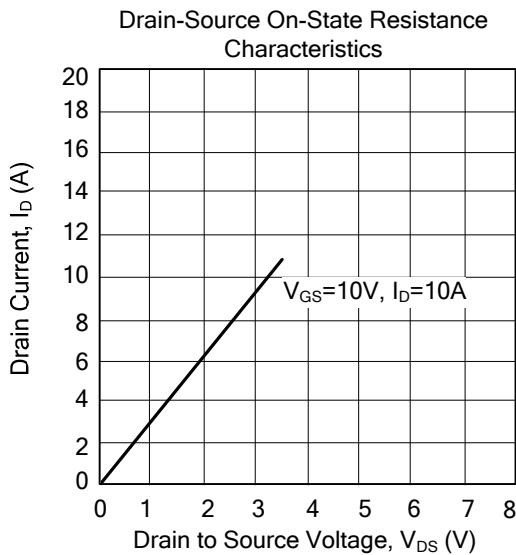
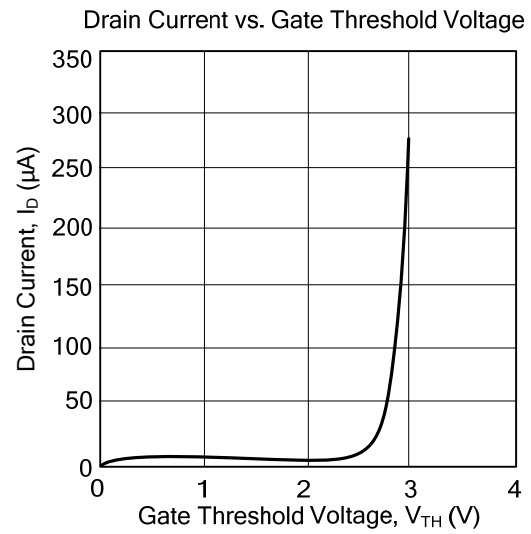
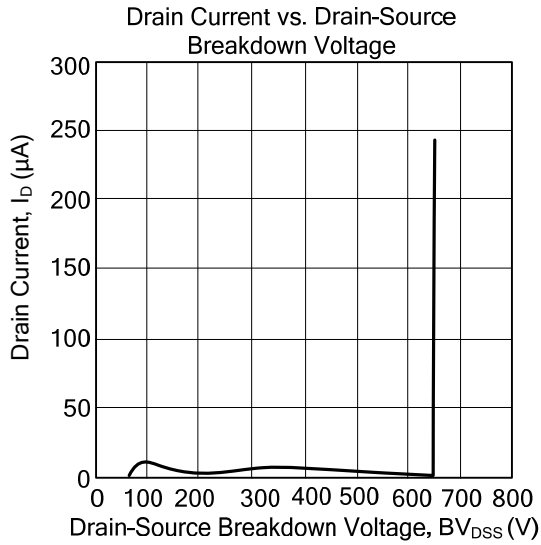
■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	600			V	
Drain-Source Leakage Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V			10	μA	
Gate- Source Leakage Current	Forward	V _{GS} =+20V, V _{DS} =0V			+100	nA	
	Reverse	V _{GS} =-20V, V _{DS} =0V			-100	nA	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	2		4.0	V	
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =10A, Pulse test, t≤300μs, duty cycle d≤2%		0.32	0.45	Ω	
DYNAMIC PARAMETERS							
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1MHz		4500		pF	
Output Capacitance	C _{OSS}				330		pF
Reverse Transfer Capacitance	C _{RSS}				140		pF
SWITCHING PARAMETERS							
Total Gate Charge	Q _G	V _{GS} =10V, V _{DS} =300V, I _D =10A (Note 1, 2)			170	nC	
Gate to Source Charge	Q _{GS}				40	nC	
Gate to Drain Charge	Q _{GD}				85	nC	
Turn-ON Delay Time	t _{D(ON)}	V _{GS} =10V, V _{DS} =300V, I _D =10A, R _G =2Ω, (Note 1, 2)		110	40	ns	
Rise Time	t _R			130	60	ns	
Turn-OFF Delay Time	t _{D(OFF)}			800	90	ns	
Fall-Time	t _F			170	60	ns	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Maximum Body-Diode Continuous Current	I _S	V _{GS} =0V			20	A	
Maximum Body-Diode Pulsed Current	I _{SM}	Repetitive			80	A	
Drain-Source Diode Forward Voltage	V _{SD}	I _F =I _S , V _{GS} =0V, Pulse test, t≤300μs, duty cycle d≤2%			1.5	V	
Body Diode Reverse Recovery Time	t _{rr}	I _F =I _S , V _R =100V, -di/dt=100A/μs(Note 1)		600		ns	

Notes: 1. Pulse Test: Pulse width ≤ 300μs, Duty cycle ≤ 2%

2. Essentially independent of operating temperature

■ TYPICAL CHARACTERISTICS



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